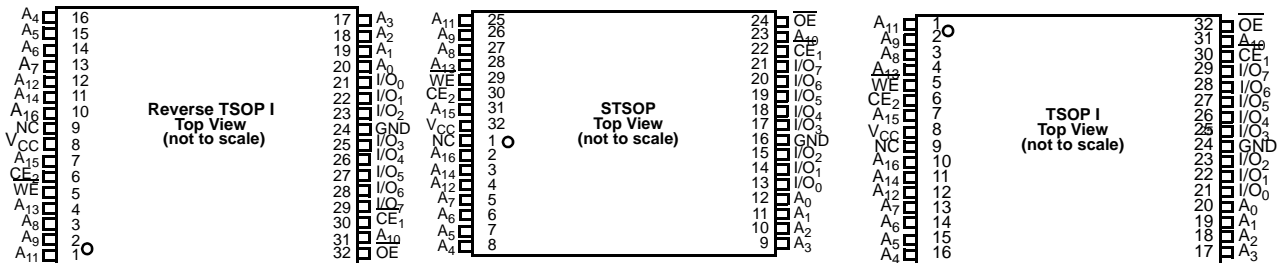
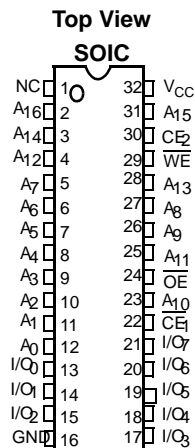


**Product Portfolio**

Product		V <sub>CC</sub> Range (V)			Speed (ns)	Power Dissipation			
						Operating, I <sub>CC</sub> (mA)		Standby, I <sub>SB2</sub> (μA)	
		Min.	Typ. <sup>[2]</sup>	Max.		Typ. <sup>[2]</sup>	Max.	Typ. <sup>[2]</sup>	Max.
CY62128BLL	Industrial	4.5	5.0	5.5	55	7.5	20	2.5	15
	Industrial				70	6	15	2.5	15
	Automotive				70	6	25	2.5	25

**Pin Configurations**

**Pin Definitions**

Input	<b>A<sub>0</sub>-A<sub>16</sub></b> . Address Inputs
Input/Output	<b>I/O<sub>0</sub>-I/O<sub>7</sub></b> . Data lines. Used as input or output lines depending on operation
Input/Control	<b>WE</b> . Write Enable, Active LOW. When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted.
Input/Control	<b>CE<sub>1</sub></b> . Chip Enable 1, Active LOW.
Input/Control	<b>CE<sub>2</sub></b> . Chip Enable 2, Active HIGH.
Input/Control	<b>OE</b> . Output Enable, Active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins behave as outputs. When deasserted HIGH, I/O pins are three-stated, and act as input data pins
Ground	<b>GND</b> . Ground for the device
Power Supply	<b>V<sub>CC</sub></b> . Power supply for the device

**Note:**

- Typical values are included for reference only and are not tested or guaranteed. Typical values are an average of the distribution across normal production variations as measured at V<sub>CC</sub> = 5.0V, T<sub>A</sub> = 25°C, and t<sub>AA</sub> = 70 ns.

## Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... -65°C to +150°C

Ambient Temperature with

Power Applied ..... -55°C to +125°C

Supply Voltage on  $V_{CC}$  to Relative GND<sup>[3]</sup> .... -0.5V to +7.0V

DC Voltage Applied to Outputs

in High-Z State<sup>[3]</sup> ..... -0.5V to  $V_{CC} + 0.5V$

DC Input Voltage<sup>[3]</sup> ..... -0.5V to  $V_{CC} + 0.5V$

Current into Outputs (LOW) ..... 20 mA

Static Discharge Voltage ..... > 2001V  
(per MIL-STD-883, Method 3015)

Latch-up Current ..... > 200 mA

## Operating Range

Range	Ambient Temperature ( $T_A$ ) <sup>[4]</sup>	$V_{CC}$
Commercial	0°C to +70°C	5V ± 10%
Industrial	-40°C to +85°C	5V ± 10%
Automotive	-40°C to +125°C	5V ± 10%

## Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	CY62128B-55			CY62128B-70			Unit
			Min.	Typ. <sup>[2]</sup>	Max.	Min.	Typ. <sup>[2]</sup>	Max.	
$V_{OH}$	Output HIGH Voltage	$V_{CC} = \text{Min.}, I_{OH} = -1.0 \text{ mA}$	2.4			2.4			V
$V_{OL}$	Output LOW Voltage	$V_{CC} = \text{Min.}, I_{OL} = 2.1 \text{ mA}$			0.4			0.4	V
$V_{IH}$	Input HIGH Voltage		2.2		$V_{CC} + 0.3$	2.2		$V_{CC} + 0.3$	V
$V_{IL}$	Input LOW Voltage <sup>[3]</sup>		-0.3		0.8	-0.3		0.8	V
$I_{IX}$	Input Load Current	$GND \leq V_I \leq V_{CC}$	-1		+1	-1		+1	μA
		Automotive				-10		+10	μA
$I_{OZ}$	Output Leakage Current	$GND \leq V_I \leq V_{CC}$ , Output Disabled	-1		+1	-1		+1	μA
		Automotive				-10		+10	μA
$I_{OS}$	Output Short Circuit Current <sup>[5]</sup>	$V_{CC} = \text{Max.}, V_{OUT} = GND$			-300			-300	mA
$I_{CC}$	$V_{CC}$ Operating Supply Current	$V_{CC} = \text{Max.}, I_{OUT} = 0 \text{ mA}, f = f_{MAX} = 1/t_{RC}$		7.5	20		6	15	mA
		Industrial, Commercial					6	25	mA
		Automotive					6	25	mA
$I_{SB1}$	Automatic CE Power-down Current —TTL Inputs	Max. $V_{CC}$ , $\overline{CE}_1 \geq V_{IH}$ or $\overline{CE}_2 \leq V_{IL}$ , $V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}$ , $f = f_{MAX}$		0.1	2		0.1	1	mA
		Industrial Commercial					0.1	2	mA
		Automotive					0.1	2	mA
$I_{SB2}$	Automatic CE Power-down Current —CMOS Inputs	Max. $V_{CC}$ , $\overline{CE}_1 \geq V_{CC} - 0.3V$ , or $\overline{CE}_2 \leq 0.3V$ , $V_{IN} \geq V_{CC} - 0.3V$ , or $V_{IN} \leq 0.3V$ , $f = 0$		2.5	15		2.5	15	μA
		Industrial Commercial					2.5	15	μA
		Automotive					2.5	25	μA

### Notes:

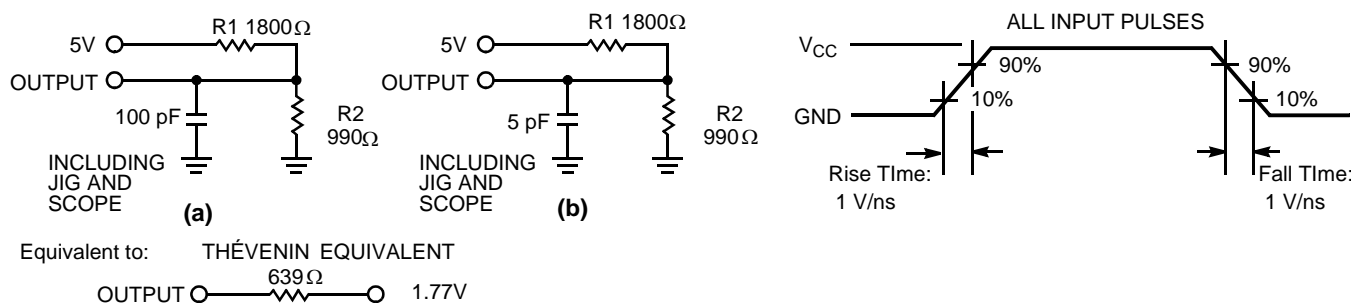
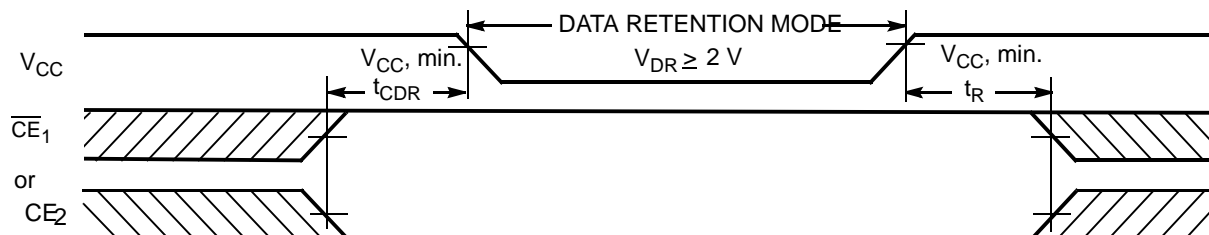
- $V_{IL}$  (min.) = -2.0V for pulse durations of less than 20 ns.
- $T_A$  is the "Instant On" case temperature.
- Not more than one output should be shorted at one time. Duration of the short circuit should not exceed 30 seconds.

**Thermal Resistance<sup>[6]</sup>**

Parameter	Description	Test Conditions	32 SOIC	32 TSOP	32 STSOP	32 RTSOP	Unit
$\Theta_{JA}$	Thermal Resistance (Junction to Ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA / JESD51.	66.17	97.44	105.14	97.44	°C/W
$\Theta_{JC}$	Thermal Resistance (Junction to Case)		30.87	26.05	14.09	26.05	°C/W

**Capacitance<sup>[6]</sup>**

Parameter	Description	Test Conditions	Max.	Unit
$C_{IN}$	Input Capacitance	$T_A = 25^\circ\text{C}$ , $f = 1\text{ MHz}$ , $V_{CC} = 5.0\text{V}$	9	pF
$C_{OUT}$	Output Capacitance		9	pF

**AC Test Loads and Waveforms**

**Data Retention Waveform**

**Data Retention Characteristics (Over the Operating Range for "LL" version only)**

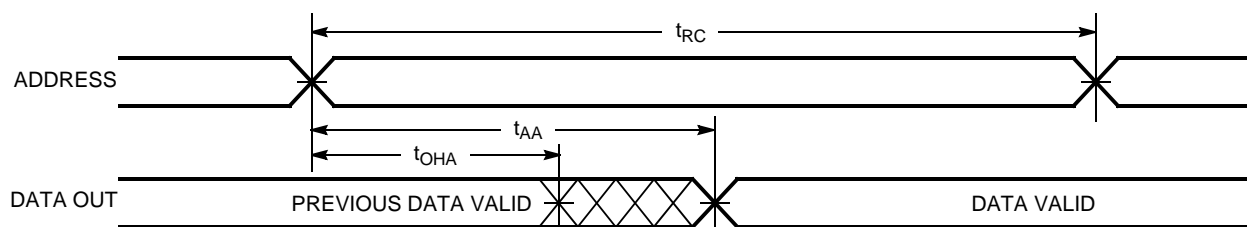
Parameter	Description	Conditions	Min.	Typ.	Max.	Unit
$V_{DR}$	$V_{CC}$ for Data Retention		2.0			V
$I_{CCDR}$	Data Retention Current	$V_{CC} = V_{DR} = 2.0\text{V}$ , $\overline{CE}_1 \geq V_{CC} - 0.3\text{V}$ , or $CE_2 \leq 0.3\text{V}$ , $V_{IN} \geq V_{CC} - 0.3\text{V}$ or, $V_{IN} \leq 0.3\text{V}$		1.5	15	μA
$t_{CDR}$	Chip Deselect to Data Retention Time		0			ns
$t_R$	Operation Recovery Time		70			ns

**Note:**

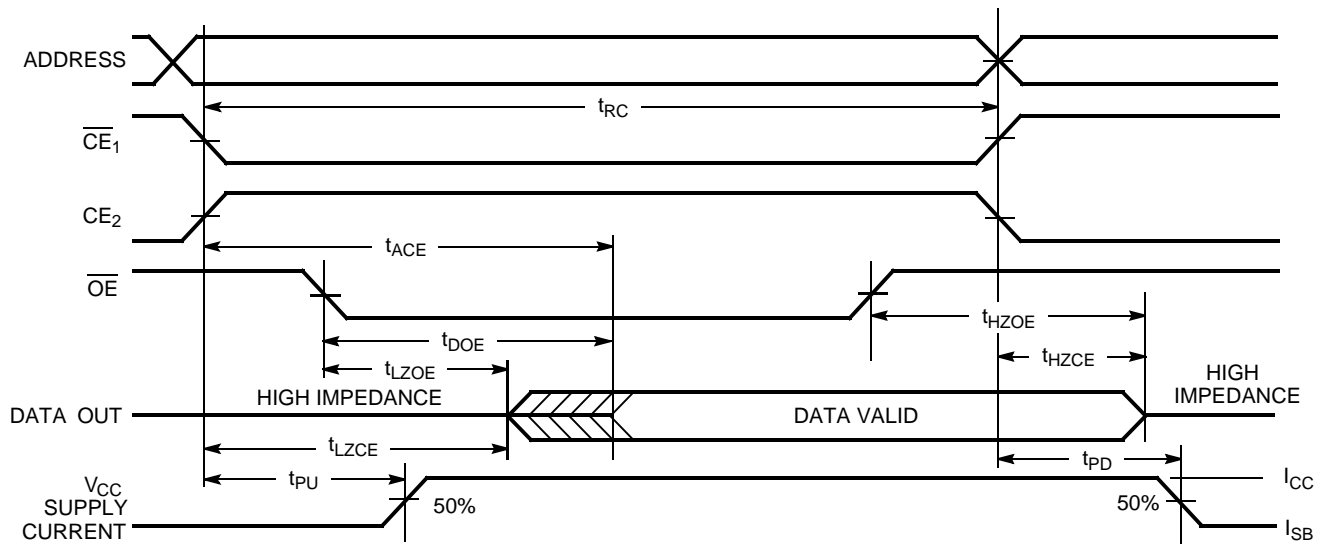
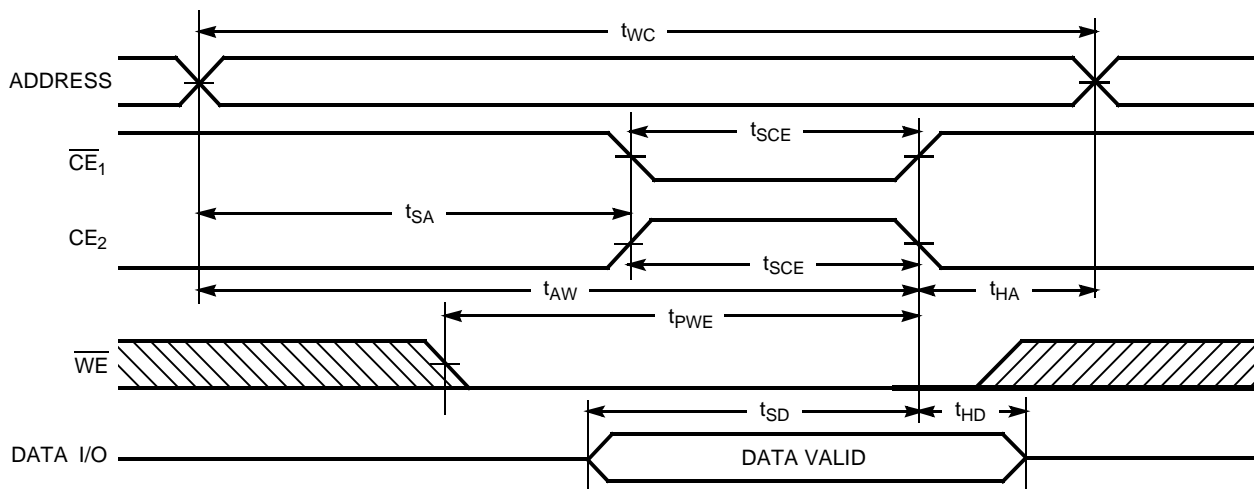
6. Tested initially and after any design or process changes that may affect these parameters.

**Switching Characteristics<sup>[7]</sup> Over the Operating Range**

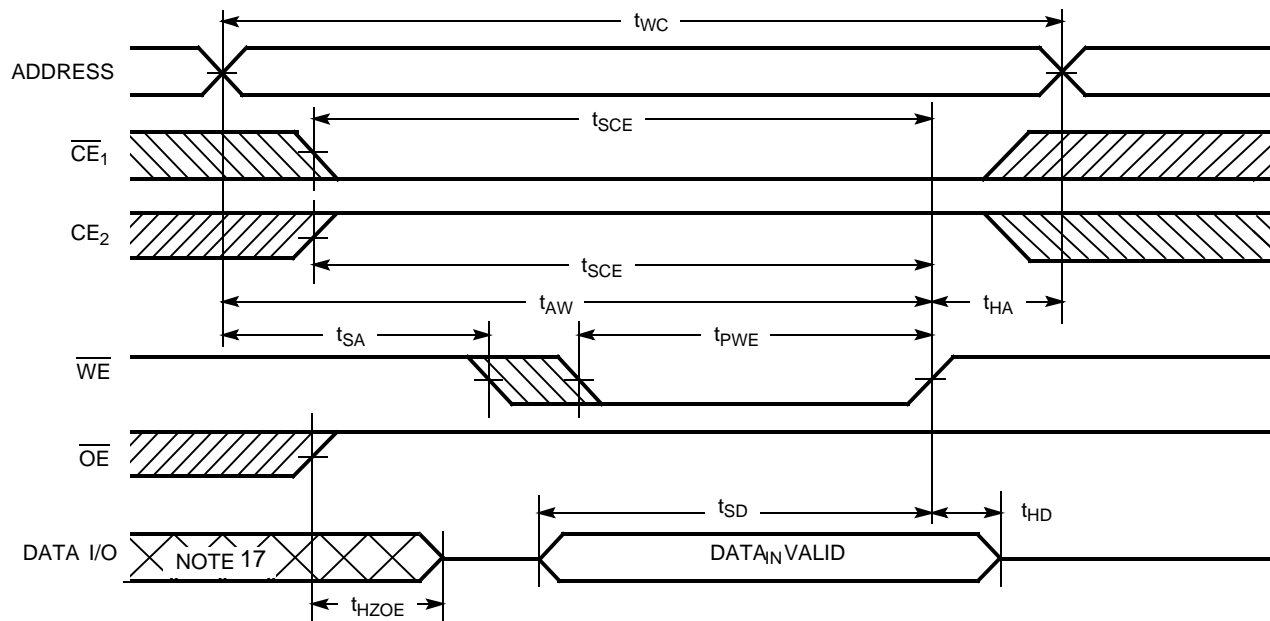
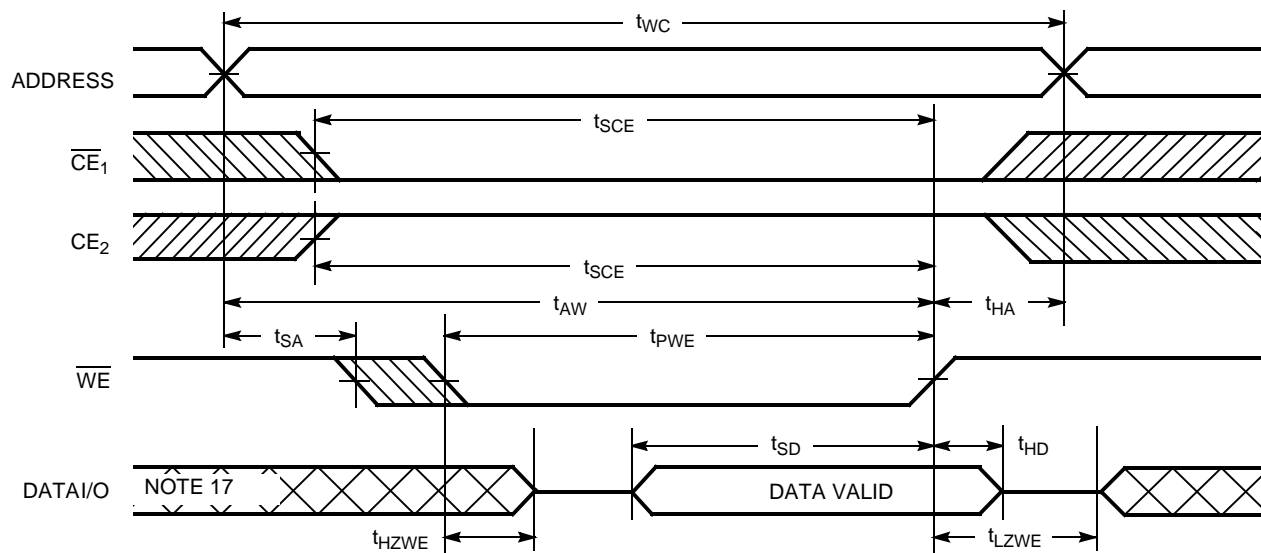
Parameter	Description	62128B-55		62128B-70		Unit
		Min.	Max.	Min.	Max.	
READ CYCLE						
t <sub>RC</sub>	Read Cycle Time	55		70		ns
t <sub>AA</sub>	Address to Data Valid		55		70	ns
t <sub>OHA</sub>	Data Hold from Address Change	5		5		ns
t <sub>ACE</sub>	$\overline{CE}_1$ LOW to Data Valid, CE <sub>2</sub> HIGH to Data Valid		55		70	ns
t <sub>DOE</sub>	$\overline{OE}$ LOW to Data Valid		20		35	ns
t <sub>LZOE</sub>	$\overline{OE}$ LOW to Low Z	0		0		ns
t <sub>HZOE</sub>	$\overline{OE}$ HIGH to High Z <sup>[7, 9]</sup>		20		25	ns
t <sub>LZCE</sub>	$\overline{CE}_1$ LOW to Low Z, CE <sub>2</sub> HIGH to Low Z <sup>[9]</sup>	5		5		ns
t <sub>HZCE</sub>	$\overline{CE}_1$ HIGH to High Z, CE <sub>2</sub> LOW to High Z <sup>[8, 9]</sup>		20		25	ns
t <sub>PU</sub>	$\overline{CE}_1$ LOW to Power-up, CE <sub>2</sub> HIGH to Power-up	0		0		ns
t <sub>PD</sub>	$\overline{CE}_1$ HIGH to Power-down, CE <sub>2</sub> LOW to Power-down		55		70	ns
WRITE CYCLE <sup>[10]</sup>						
t <sub>WC</sub>	Write Cycle Time	55		70		ns
t <sub>SCE</sub>	$\overline{CE}_1$ LOW to Write End, CE <sub>2</sub> HIGH to Write End	45		60		ns
t <sub>AW</sub>	Address Set-up to Write End	45		60		ns
t <sub>HA</sub>	Address Hold from Write End	0		0		ns
t <sub>SA</sub>	Address Set-up to Write Start	0		0		ns
t <sub>PWE</sub>	$\overline{WE}$ Pulse Width	45		50		ns
t <sub>SD</sub>	Data Set-up to Write End	25		30		ns
t <sub>HD</sub>	Data Hold from Write End	0		0		ns
t <sub>LZWE</sub>	$\overline{WE}$ HIGH to Low Z <sup>[9]</sup>	5		5		ns
t <sub>HZWE</sub>	$\overline{WE}$ LOW to High Z <sup>[8, 9]</sup>		20		25	ns

**Switching Waveforms**
**Read Cycle No.1<sup>[12, 13]</sup>**

**Notes:**

- Test conditions assume signal transition time of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified  $I_{OL}/I_{OH}$  and 100-pF load capacitance.
- $t_{HZOE}$ ,  $t_{HZCE}$ , and  $t_{HZWE}$  are specified with a load capacitance of 5 pF as in (b) of AC Test Loads. Transition is measured  $\pm 500$  mV from steady-state voltage.
- At any given temperature and voltage condition,  $t_{HZCE}$  is less than  $t_{LZCE}$ ,  $t_{HZOE}$  is less than  $t_{LZOE}$ , and  $t_{HZWE}$  is less than  $t_{LZWE}$  for any given device.
- The internal write time of the memory is defined by the overlap of  $\overline{CE}_1$  LOW,  $CE_2$  HIGH, and  $\overline{WE}$  LOW.  $\overline{CE}_1$  and  $\overline{WE}$  must be LOW and  $CE_2$  HIGH to initiate a write, and the transition of any of these signals can terminate the write. The input data set-up and hold timing should be referenced to the leading edge of the signal that terminates the write.
- No input may exceed  $V_{CC} + 0.5V_{CC}$ .
- Device is continuously selected.  $\overline{OE}$ ,  $\overline{CE}_1 = V_{IL}$ ,  $CE_2 = V_{IH}$ .
- $\overline{WE}$  is HIGH for read cycle.

**Switching Waveforms (continued)**
**Read Cycle No. 2 ( $\overline{OE}$  Controlled)<sup>[13, 14]</sup>**

**Write Cycle No. 1 ( $\overline{CE}_1$  or  $CE_2$  Controlled)<sup>[15, 16]</sup>**

**Notes:**

14. Address valid prior to or coincident with  $\overline{CE}_1$  transition LOW and  $CE_2$  transition HIGH.
15. Data I/O is high impedance if  $\overline{OE} = V_{IH}$ .
16. If  $\overline{CE}_1$  goes HIGH or  $CE_2$  goes LOW simultaneously with  $\overline{WE}$  going HIGH, the output remains in a high-impedance state.

**Switching Waveforms (continued)**
**Write Cycle No. 2 ( $\overline{\text{WE}}$  Controlled,  $\overline{\text{OE}}$  HIGH During Write)<sup>[15, 16]</sup>**

**Write Cycle No.3 ( $\overline{\text{WE}}$  Controlled,  $\overline{\text{OE}}$  LOW)<sup>[15, 16]</sup>**

**Note:**

17. During this period the I/Os are in the output state and input signals should not be applied.

**Truth Table**

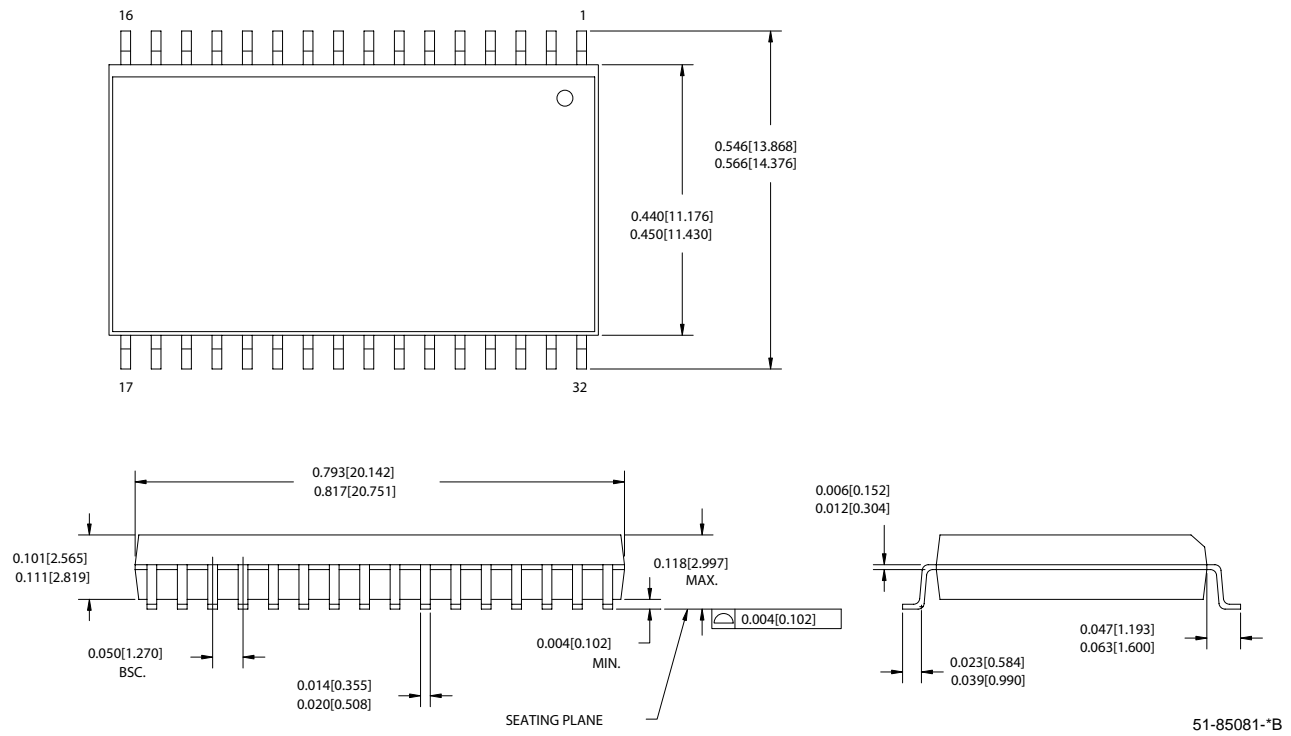
$\overline{CE}_1$	$\overline{CE}_2$	$\overline{OE}$	$\overline{WE}$	I/O <sub>0</sub> -I/O <sub>7</sub>	Mode	Power
H	X	X	X	High Z	Power-down	Standby (I <sub>SB</sub> )
X	L	X	X	High Z	Power-down	Standby (I <sub>SB</sub> )
L	H	L	H	Data Out	Read	Active (I <sub>CC</sub> )
L	H	X	L	Data In	Write	Active (I <sub>CC</sub> )
L	H	H	H	High Z	Selected, Outputs Disabled	Active (I <sub>CC</sub> )

**Ordering Information**

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
55	CY62128BLL-55SI	S34	32-Lead 450-Mil SOIC	Industrial
	CY62128BLL-55SXI	S34	32-Lead 450-Mil SOIC (Pb-Free)	Industrial
	CY62128BLL-55SC	S34	32-Lead 450-Mil SOIC	Commercial
	CY62128BLL-55SXC	S34	32-Lead 450-Mil SOIC (Pb-Free)	Commercial
	CY62128BLL-55ZI	Z32	32-Lead TSOP Type I	Industrial
	CY62128BLL-55ZXI	Z32	32-Lead TSOP Type I (Pb-Free)	Industrial
	CY62128BLL-55ZAI	ZA32	32-Lead STSOP Type I	Industrial
	CY62128BLL-55ZAXI	ZA32	32-Lead STSOP Type I (Pb-Free)	Industrial
	CY62128BLL-55ZRI	ZR32	32-Lead Reverse TSOP Type I	Industrial
70	CY62128BLL-70SI	S34	32-Lead 450-Mil SOIC I	Industrial
	CY62128BLL-70SXI	S34	32-Lead 450-Mil SOIC I (Pb-Free)	Industrial
	CY62128BLL-70SC	S34	32-Lead 450-Mil SOIC I	Commercial
	CY62128BLL-70SXC	S34	32-Lead 450-Mil SOIC I (Pb-Free)	Commercial
	CY62128BLL-70SE	S34	32-Lead 450-Mil SOIC I	Automotive
	CY62128BLL-70SXE	S34	32-Lead 450-Mil SOIC I (Pb-Free)	Automotive
	CY62128BLL-70ZI	Z32	32-Lead TSOP Type I	Industrial
	CY62128BLL-70ZC	Z32	32-Lead TSOP Type I	Commercial
	CY62128BLL-70ZE	Z32	32-Lead TSOP Type I	Automotive
	CY62128BLL-70ZXE	Z32	32-Lead TSOP Type I (Pb-Free)	Automotive
	CY62128BLL-70ZAI	ZA32	32-Lead STSOP Type I	Industrial
	CY62128BLL-70ZAXI	ZA32	32-Lead STSOP Type I (Pb-Free)	Industrial
	CY62128BLL-70ZAE	ZA32	32-Lead STSOP Type I	Automotive
	CY62128BLL-70ZAXE	ZA32	32-Lead STSOP Type I (Pb-Free)	Automotive
	CY62128BLL-70ZRXE	ZR32	32-Lead Reverse TSOP Type I (Pb-Free)	Automotive

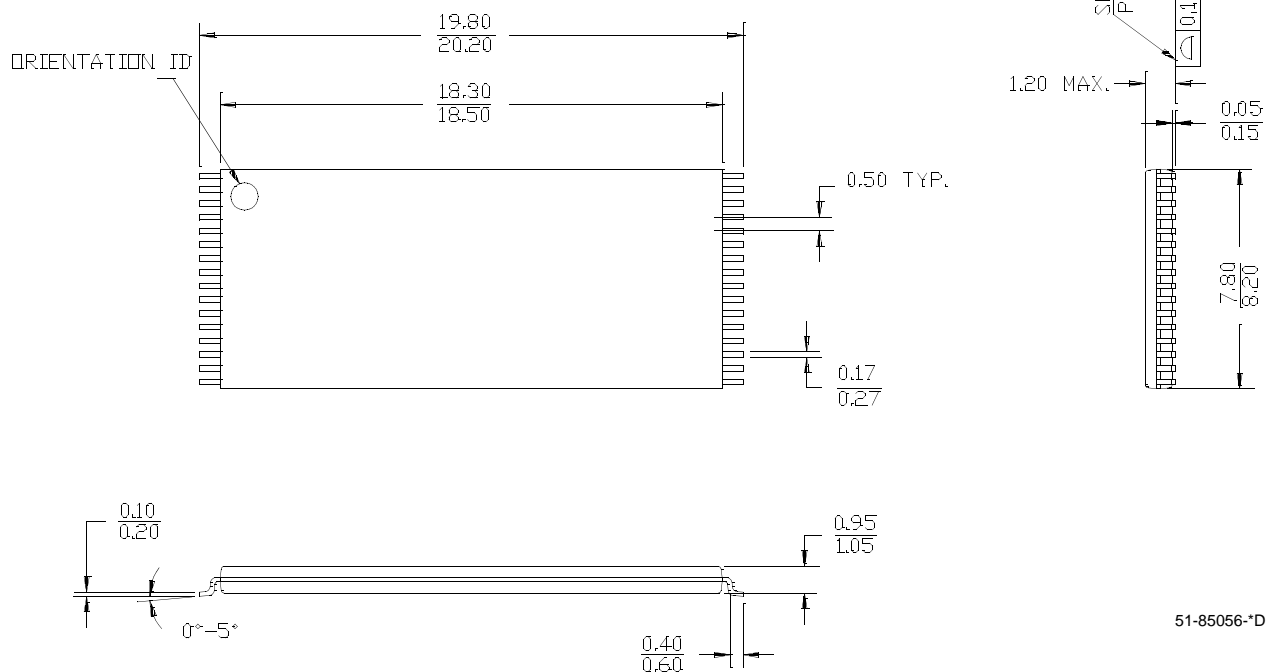
Package Diagrams

32-Lead (450 MIL) Molded SOIC S34



32-Lead Thin Small Outline Package Type I (8x20 mm) Z32

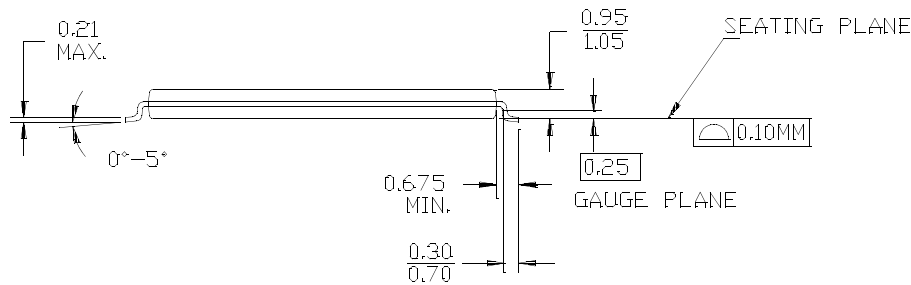
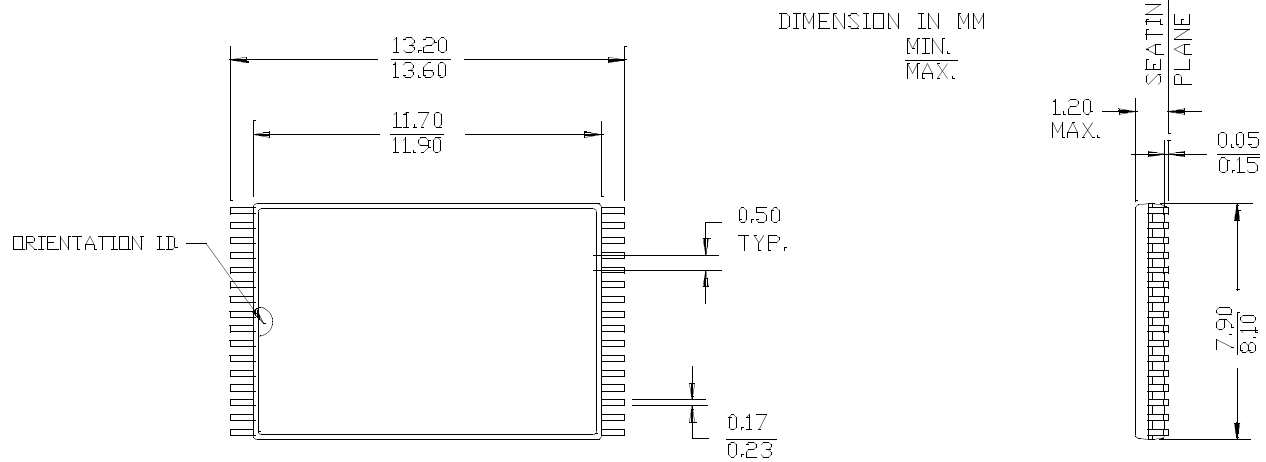
DIMENSION IN MM  
MIN.  
MAX.



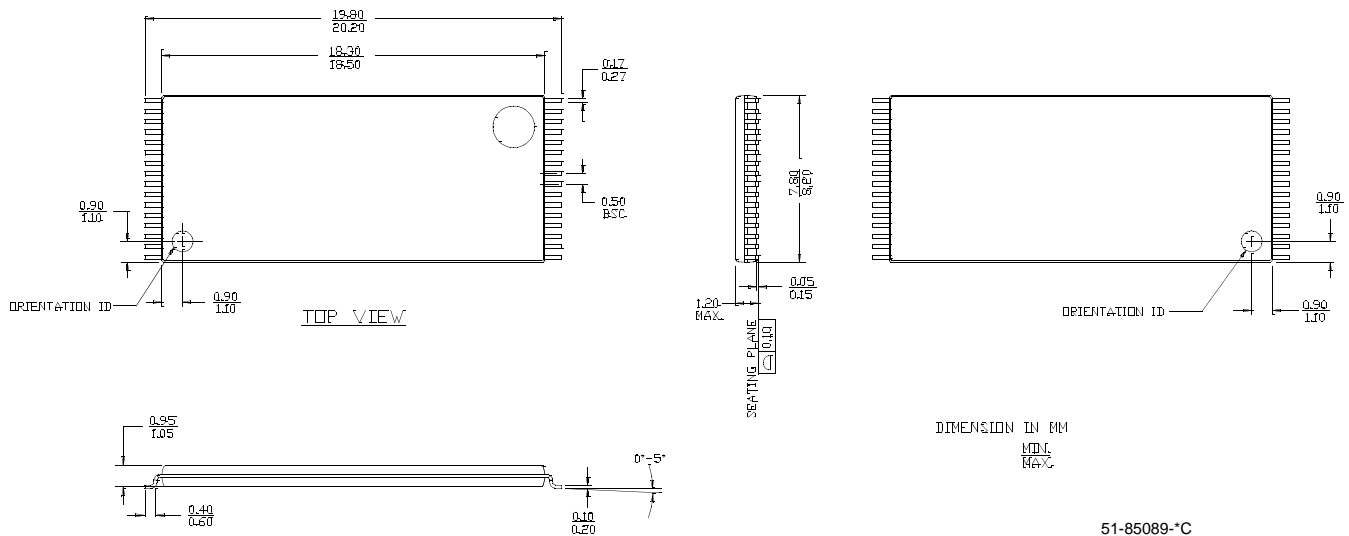


Package Diagrams (continued)

32-Lead Shrunken Thin Small Outline Package (8x13.4 mm) ZA32



32-Lead Reverse Thin Small Outline Package ZR32



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**Document History Page**

Document Title: CY62128B MoBL <sup>®</sup> 1-Mbit (128K x 8) Static RAM Document Number: 38-05300				
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change
**	116566	06/20/02	DSG	Changed from Spec number: 38-00524 to 38-05300
*A	126601	06/09/03	JUI	Changed CE to CE <sub>1</sub> and added CE <sub>2</sub> ≤ 0.3V in Data Retention Characteristics table Removed these part numbers from Ordering Information table: CY62128BLL-55ZC, CY62128BLL-55ZAC, CY62128BLL-55ZRC, CY62128BLL-70ZAC, CY62128BLL-70ZRI, CY62128BLL-70ZRC
*B	239134	See ECN	AJU	Added Thermal Resistance table Added Automotive product information
*C	334398	See ECN	SYT	Added Pb-Free part numbers to the Ordering info on Page #8